Datasheet



SiC Schottky Barrier Diode

V_R	650V
l _F	6A
Q_C	19nC

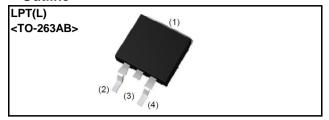
Features

- 1) Low forward voltage
- 2) Negligible recovery time/current
- 3) Temperature independent switching behavior
- 4) High surge current capability
- 5) Low leakage current

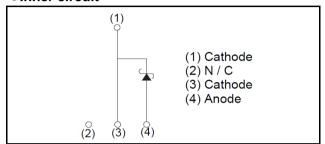
Applications

- Switch Mode Power Supply
- Uninterruptible Power Supply
- ·Solar Inverter
- Motor Drive
- · Air Conditioner
- •EV Charger

Outline



•Inner circuit



Packaging specifications

or actuality operations			
Packaging Reel size (mm)		Embossed tape	
		330	
Tuno	Tape width (mm)	24	
Туре	Basic ordering unit (pcs)	1.000	
	Packing code	TLL	
	Marking	SCS306AJ	

● Absolute maximum ratings (T_i = 25°C)

Parameter		Symbol	Value	Unit
Reverse voltage (re	petitive peak)	V_{RM}	650	V
Reverse voltage (DC	C)	V _R	650	V
Continuous forward	current (T _c = 140°C)	I _F	6	А
Surge non-	PW=10ms sinusoidal, T _j =25°C		47	А
repetitive forward PW=10ms sinusoidal, T _j =150°C		I _{FSM}	39	А
current	PW=10μs square, T _j =25°C		170	А
Repetitive peak forward current		I _{FRM}	29 ^{*1}	А
1≦PW≦10ms, T _j =25°C		$\int i^2 dt$	11	A ² s
i ² t value 1≦PW≦10ms, T _j =150°C		J I⁻at	7	A ² s
Total power disspation		P_{D}	50 ^{*2}	W
Junction temperature		T _j	175	°C
Range of storage temperature		T_{stg}	-55 to +175	°C

^{*1} T_c=100°C, T_i=150°C, Duty cycle=10% *2 T_c=25°C

•Electrical characteristic curves

Fig.1 V_F - I_F Characteristics

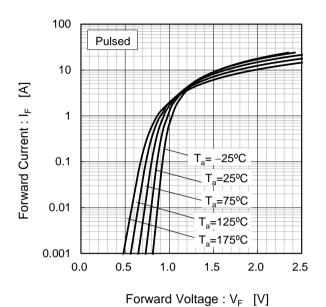
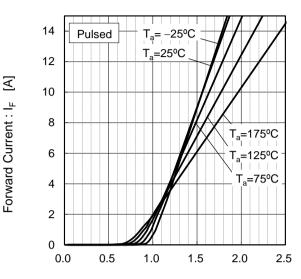


Fig.2 V_F - I_F Characteristics



Forward Voltage : V_F [V]

Fig.3 V_R - I_R Characteristics

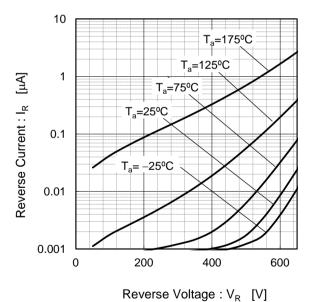
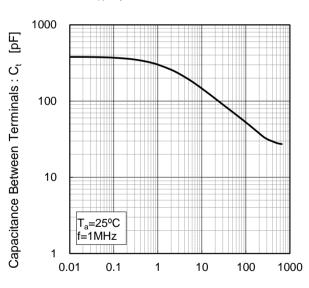


Fig.4 V_R-C_t Characteristics



Reverse Voltage : V_R [V]

●Electrical characteristics (T_i = 25°C)

Parameter	Symbol	Conditions	Values			Unit
			Min.	Тур.	Max.	Offit
DC blocking voltage	V_{DC}	I _R =30μA	650	-	-	V
	V _F	I _F =6A,T _j =25°C	-	1.35	1.50	V
Forward voltage		I _F =6A,T _j =150°C	-	1.44	1.71	V
		I _F =6A,T _j =175°C	-	1.50	-	V
Reverse current	I _R	V _R =650V,T _j =25°C	-	0.018	30	μΑ
		V _R =650V,T _j =150°C	-	1.2	120	μΑ
		V _R =650V,T _j =175°C	-	3.6	-	μА
Total capacitance	С	V _R =1V,f=1MHz	-	300	-	pF
		V _R =650V,f=1MHz	-	27	-	pF
Total capacitive charge	Q_{C}	V _R =400V,di/dt=350A/μs	-	19	-	nC
Switching time	t _C	V _R =400V,di/dt=350A/μs	-	15	-	ns
Non-repetetive Avaranche Energy	E _{ava}	L=1mH	-	71	-	mJ

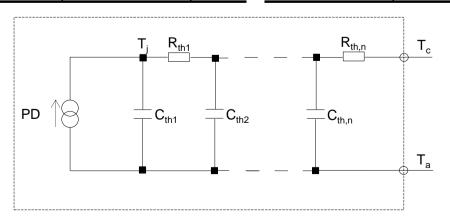
●Thermal characteristics

Parameter	Symbol	Conditions	Values			Unit
			Min.	Тур.	Max.	Offic
Thermal resistance	R _{th(j-c)}	-	ı	2.1	3.0	°C/W

●Typical Transient Thermal Characteristics

Symbol	Value	Unit
R _{th1}	2.92E-01	
R _{th2}	1.80E+00	K/W
R _{th3}	9.97E-03	

Symbol	Value	Unit
C _{th1}	1.26E-04	
C _{th2}	1.51E-03	Ws/K
C _{th3}	2.98E-01	



1.000

Electrical characteristic curves

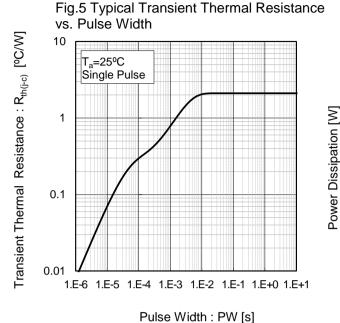
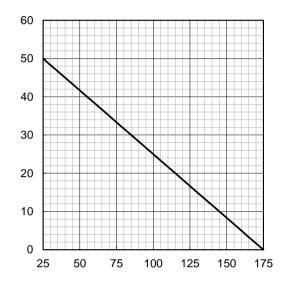


Fig.6 Power Dissipation



Case Temperature : T_c [°C]

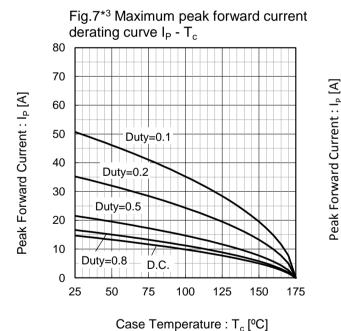
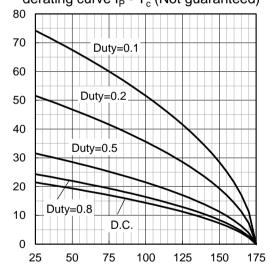


Fig.8*4 Typical peak forward current derating curve I_P - T_c (Not guaranteed)



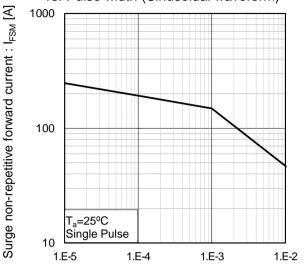
*3 Based on max Vf, max R_{th(j-c)} Valid for switching of above 10kHz, excluding D.C. curve.

Case Temperature : T_c [°C]

*4 Based on typ Vf, typ R_{th(j-c)}
Typical value, not guaranteed
Valid for switching of above 10kHz,
excluding D.C. curve

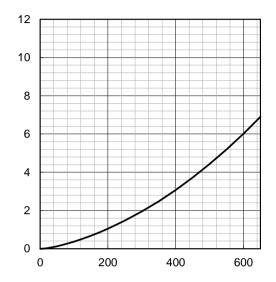
Electrical characteristic curves

Fig.9 Surge non-repetitive forward current vs. Pulse width (Sinusoidal waveform)



Pulse Width: PW [s]

Fig.10 Typical capacitance store energy

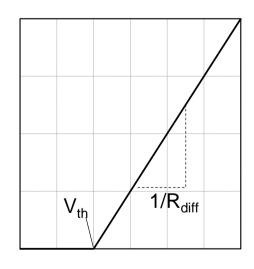


Capacitance stored energy : $E_{c}[\mu J]$

Reverse Voltage : V_R [V]

Symplified forward characteristic model

Fig.11 Equivalent forward current curve



Forward Voltage: V_F

$$V_F = V_{th} + R_{diff} I_F$$

$$V_{th} (T_j) = a_0 + a_1 T_j$$

 $R_{diff} (T_j) = b_0 + b_1 T_j + b_2 T_j^2$

Symbol	Typical Value Unit	
a ₀	9.66E-01	V
a ₁	-1.10E-03	V/°C
b ₀	5.87E-02	Ω
b ₁	1.24E-04	Ω/°C
b ₂	1.28E-06	$\Omega/^{\circ}C^{2}$

 T_i in °C; -55 °C < T_i < 175°C; I_F < 12 A

Forward Current: IF

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SCS306AJ - Web Page

Part Number	SCS306AJ
Package	TO-263AB (LPTL)
Unit Quantity	1000
Minimum Package Quantity	1000
Packing Type	Taping
Constitution Materials List	inquiry
RoHS	Yes